

#### 1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in an ultra small DFN1110D-3 (SOT8015) leadless Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

#### 2. Features and benefits

- · Logic-level compatible
- Side wettable flanks for optical solder inspection
- Ultra small and leadless SMD plastic package: 1.1 x 1 x 0.48 mm
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 1 kV HBM (Class H1C)
- AEC-Q101 qualified

#### 3. Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

#### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	60	V
V <sub>GS</sub>	gate-source voltage			-16	-	16	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C	[1]	-	-	720	mA
Static characte	ristics						
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 720 mA; T <sub>j</sub> = 25 °C		-	635	850	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.

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# 5. Pinning information

Table 2. F	Pinning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source	3	
3	D	drain	Transparent top view DFN1110D-3 (SOT8015)	G G S 017aaa255

# 6. Ordering information

#### Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
2N7002KQB	DFN1110D-3	plastic, leadless extremely thin small outline package with side-wettable flanks (SWF); 3 terminals; 0.65 mm pitch; 1.1 mm x 1 mm x 0.48 mm body	SOT8015		

# 7. Marking

Table 4. Marking codes	
Type number	Marking code
2N7002KQB	C7

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60 V N-channel Trench MOSFET

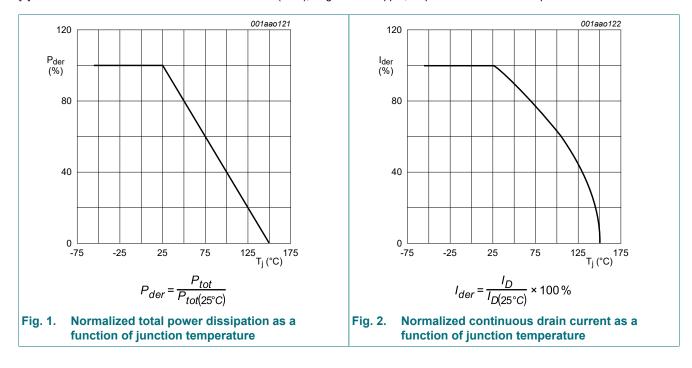
#### 8. Limiting values

#### Table 5. Limiting values

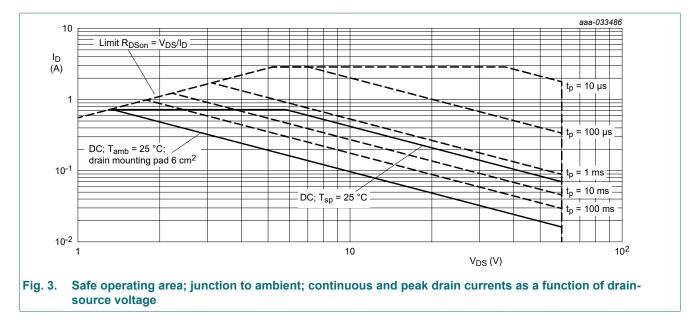
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	60	V
V <sub>GS</sub>	gate-source voltage			-16	16	V
V <sub>GSMlim</sub>	peak gate-source voltage	$\delta_{factor} = 0.1; t_p = 50 \ \mu s; T_j = 25 \ ^{\circ}C$		-20	20	V
ID	drain current	V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 25 °C	[1]	-	720	mA
		V <sub>GS</sub> = 10 V; T <sub>amb</sub> = 100 °C	[1]	-	460	mA
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	2.9	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	420	mW
			[1]	-	960	mW
		T <sub>sp</sub> = 25 °C		-	4.2	W
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-drain	n diode				-	
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	700	mA
ESD maximu	um rating	1				
V <sub>ESD</sub>	electrostatic discharge voltage	НВМ		-	1000	V
Avalanche r	uggedness				·	
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	T <sub>j(init)</sub> = 25 °C; I <sub>D</sub> = 0.05 A		-	1.5	mJ
		1				

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.
Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



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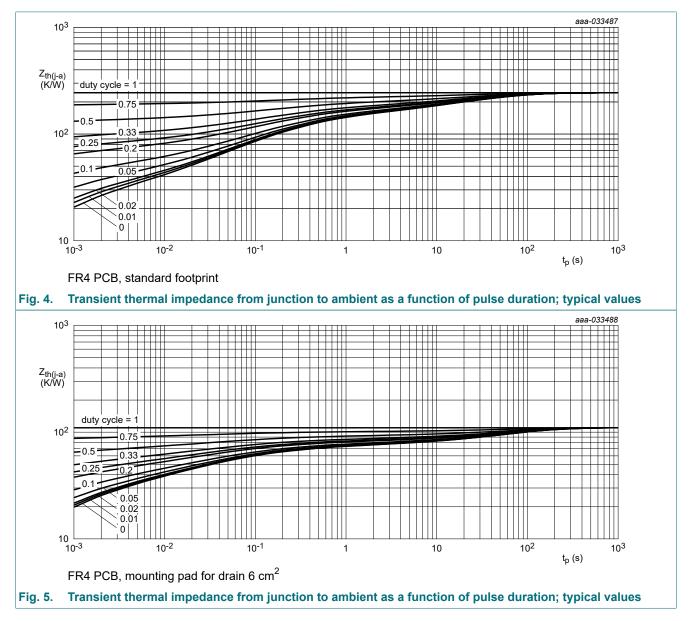
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# 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
R <sub>th(j-a)</sub> thermal resistance from	in free air	[1]	-	245	300	K/W	
	junction to ambient		[2]	-	110	130	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	25	30	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

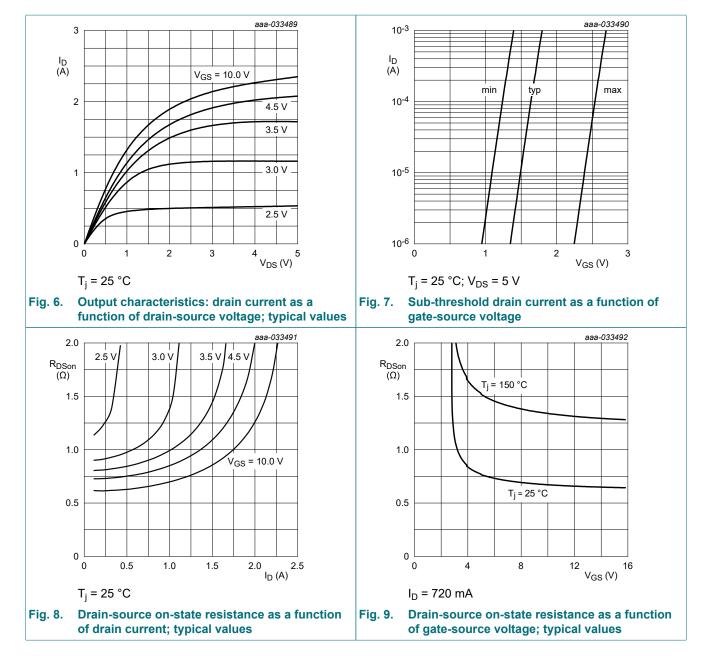
[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm<sup>2</sup>.



# **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	60	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	I <sub>D</sub> = 250 μA; V <sub>DS</sub> = V <sub>GS</sub> ; T <sub>j</sub> = 25 °C	1.3	1.7	2.6	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 60 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	1	μA
I <sub>GSS</sub> gate leakage current	$V_{GS}$ = 16 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	10	μA	
		V <sub>GS</sub> = -16 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	-10	μA
R <sub>DSon</sub>	drain-source on-state	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 720 mA; T <sub>j</sub> = 25 °C	-	635	850	mΩ
resistance	resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 720 mA; T <sub>j</sub> = 150 °C	-	1400	1800	mΩ
	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 630 mA; T <sub>j</sub> = 25 °C	-	765	1100	mΩ	
9fs	forward transconductance	V <sub>DS</sub> = 5 V; I <sub>D</sub> = 720 mA; T <sub>j</sub> = 25 °C	-	1.1	-	S
Dynamic ch	naracteristics		I			
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = 30 V; $I_{D}$ = 0.7 A; $V_{GS}$ = 10 V;	-	0.61	0.92	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	0.07	-	nC
Q <sub>GD</sub>	gate-drain charge		-	0.15	-	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 30 V; f = 1 MHz; V <sub>GS</sub> = 0 V;	-	28	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	5	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	3	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 30 V; I <sub>D</sub> = 0.7 A; V <sub>GS</sub> = 10 V;	-	1	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	1	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	6	-	ns
t <sub>f</sub>	fall time		-	3	-	ns
Source-drai	in diode					
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 0.7 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	0.7	1.2	V
t <sub>rr</sub>	reverse recovery time	$    I_{S} = 0.7 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A/s}; \\     V_{GS} = 10 \text{ V}; \text{ V}_{DS} = 30 \text{ V}; \text{ T}_{j} = 25 ^{\circ}\text{C} $	-	8	-	ns
Q <sub>r</sub>	recovered charge	I <sub>S</sub> = 0.7 A; dI <sub>S</sub> /dt = -100 A/μs; V <sub>GS</sub> = 10 V; V <sub>DS</sub> = 30 V; T <sub>i</sub> = 25 °C	-	2	-	nC

#### **60 V N-channel Trench MOSFET**

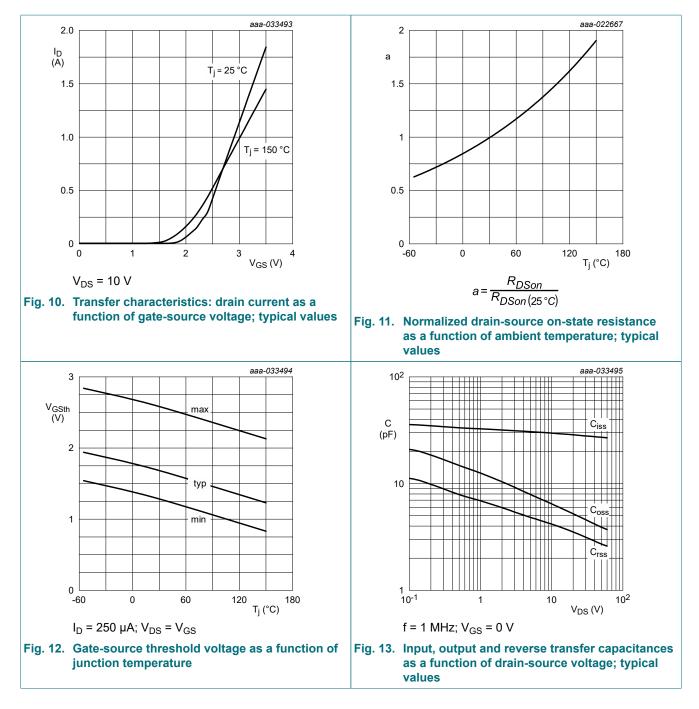


**Product data sheet** 

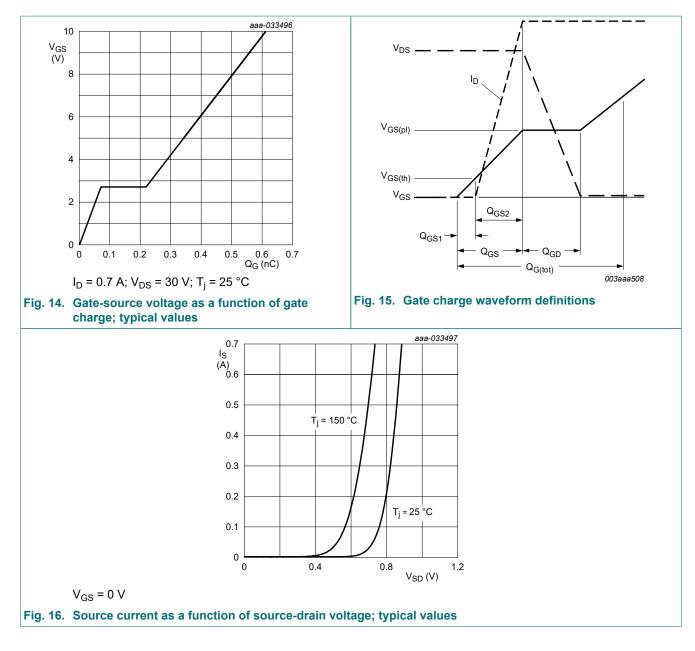
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#### 60 V N-channel Trench MOSFET



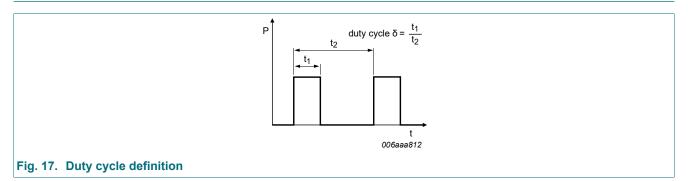
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### **11. Test information**



#### **Quality information**

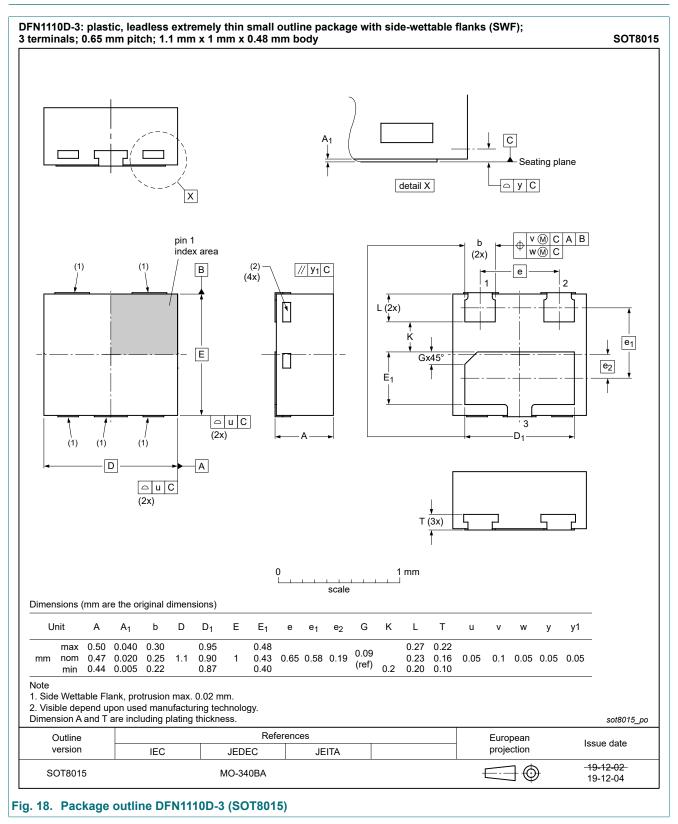
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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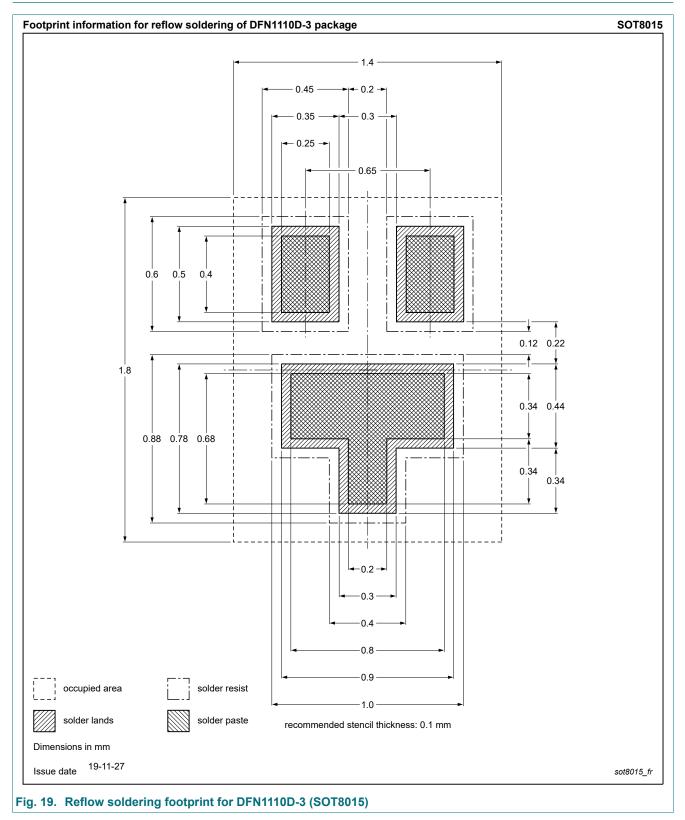
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#### 12. Package outline



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# 13. Soldering



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# 14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
2N7002KQB v.1	20210922	Product data sheet	-	-		

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### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

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